# NSN 5962-01-348-2932

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### **Body Length:**

Between 0.540 inches and 0.560 inches

#### **Body Width:**

Between 0.442 inches and 0.458 inches

## **Body Height:**

Between 0.060 inches and 0.120 inches

## Maximum Power Dissipation Rating:

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### Features Provided:

Bipolar and burn in and electrostatic sensitive and programmed

#### Inclosure Material:

Ceramic

## Inclosure Configuration:

Leadless flat pack

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### Input Circuit Pattern:

25 input

#### Case Outline Source And Designator:

C-12 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

#### **Product Name:**

Microcircuit, digital-memory

#### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### Time Rating Per Chacteristic:

45.00 nanoseconds access

#### Memory Device Type:

Ram

### Hybrid Technology Type:

Monolithic

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

32 leadless

#### Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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